Pre-power amplifier for headphone stereos BA3612AKV

The BA3612AKV is configured of a pre-amplifier and a headphone amplifier, and contains internal AMS, B.B, AVLS, and BEEP amplifier functions. Also, this IC can be used in combination with the BA3641FV to enable configuration of recording and playback sets.

Applications

Portable cassette players

Features

- 1) Low current consumption.
- 2) Internal AMS function.
- 3) Internal B.B function.
- 4) Internal AVLS function.

- 5) Internal BEEP amplifier.
- 6) Supports Dolby-B.
- 7) Supports OCL output.

● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage	Voo	5.0	V
Power dissipation	P₀	400*	mV
Operating temperature	Topr	−15~ +60	င
Storage temperature	Tstg	−55∼ +125	င

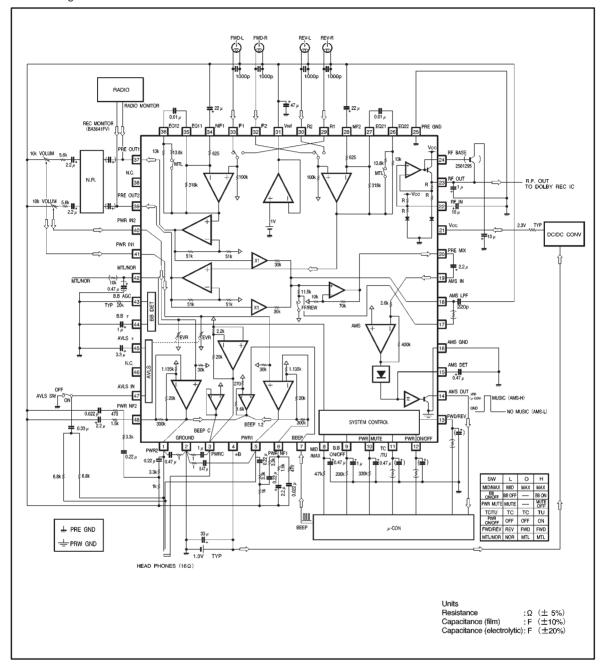
^{*}Reduced by 4.0mW for each increase in Ta of 1℃ over 25℃. when mounted on a 70mm × 70mm × 1.6mm glass epoxy board.

● Recommended operating conditions (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage 1	+B	0.90~2.20	V
Power supply voltage 2	Vcc	1.70~4.40*	V

^{*} In terms of basic operation, normally a high voltage of 0.4V higher than +B is applied for V_{∞} . A relation of $V_{\infty}=+B\times 2$ is recommended.

Block diagram



Pin descriptions

(The pin voltage of Vcc = 2.3V, +B = 1.3V is the standard value for the measurement circuit under quiescent conditions. Modes: PWR-ON, TC, FWD, NOR, Mute-OFF, B.B-OFF, AVLS-OFF)

Pin No	Pin name	DC voltage	Equivalent circuit	Function
1 5	PWR2 PWR1	0.6	Vcc	Power amplifier output BEEP amplifier output Zo ≒ 1.2Ω (power amplifier)
8	PWR NF1 PWR NF2	1.0	GND Vret SOK Vret GND	NF pin when power amplifier is B.B
2	GROUND	0	② Sub ""	PWR GND (Sub)
3	PWR C	0.6	3 3 4 Superior Superi	Power amplifier output (Center amplifier) Zo ≑ 6.7 Ω
4	+в	1.3	4) +B	Positive power supply
7	BEEP	1.0	7 1k 100k PF 100k Vref	BEEP input Zin ≒ 200kΩ
8	B.B MID / MAX	- (OPEN) 0.65 (MAX) 0.2 (MID)	300k	For bass boost MID / MAX switching
13	Forward Reverse	- (OPEN) 0.65 (FWD)	(3) GND GND TI.15V	Pre-amplifier forward/reverse input switching
42	Metal / Normal	- (OPEN) 0.2 (NOR)	GND	Pre-amplifier equalizer switching between Metal (70 μ s) and Normal (120 μ s)

Pin No.	Pin name	DC voltage	Equivalent circuit	Function
9	B.B ON / OFF	(OPEN) 0.3 (B.B-OFF)	T1.15V GND GND T1.15V	Bass boost/normal switching
10	MUTE	OPEN) 0.65 (MUTE-OFF)	10 100k 20k GND GND GND	Mute ON/OFF switching Zin=100k Ω
11	TC/TU	0 (OPEN) 0.4 (TC)	11 1k 47k 100k 100k 100k 100k 100k 100k 100k 10	Switching between TC (tape playback) and TU (radio monitor) Zin≒100kΩ
12	ST-BY (PWR ON / OFF)	0 (OPEN) 0.77 (PWR-ON)	100k 47k GND GND GND GND GND	IC power supply ON/OFF Zin≒100kΩ
14	AMSOUT	(when curve exists) 0 (when no curve exists)	VCC HB AMS GND	Mute detector output Non-mute: High Mute : Low
15	AMS DET	0 (when curve exists) 0.65 (when no curve exists)	TS TOOK TOOK TOOK TOOK TOOK TOOK TOOK TO	Mute detector comparator output smoothing pin
16	AMS GND	0 *	4MS GND	Dedicated mute detector block GND

*When GND is connected outside IC

Pin No.	Pin name	DC voltage	Equivalent circuit	Function
17	AMS LVL	1.0	30k Vcc GND	Threshold value adjustment pin for mute detector high-speed mode
18	AMS LPF	1.0	70k @0 11.5k \$ 10k	Filter configuration pin to prevent malfunction from mute detector noise Zin ≒ 1.5kΩ (for playback) Zin ≒ 7kΩ (for fast for ward / rewind)
20	PRE MIX	1.0	Vref (7)	Output pin which amplifies PRE OUT MIX output to 18 dB
19	AMS IN	1.0	AMS GND WCC AMS GND	Phase detection amplifier input for mute detector block
21	Vcc	2.3	②D VCC	Positive power supply (booster voltage)
22	RF IN	1.2	36.6k	Ripple filter amplifier input Zin≒44kΩ
23	RF OUT	2.0	GND VCC VCC VCC VCC VCC VCC VCC VCC VCC VC	Ripple filter amplifier output Zin≒56.4kΩ

Pin No.	Pin name	DC voltage	Equivalent circuit	Function
24	RF Base	1.3	20k Vcc Vcc Vcc QND 777	For connection of external transistor for ripple filter amplifier. 2SB1295 or equivalent is recommended as external transistor. See diagram below for connection.
25	Pre GND	0*	Vcc + Pre GND	Low-current GND in IC
26	EQ22	1.0	+ RF 1 29 Van	Pre-amplifier equalizer Connect capacitors between
36	EQ12	1.0	\$590 Vcc mgND	pins 26 and 27 and between pins 35 and 36.
27	EQ21	1.0	10p 14.75k 4 66	Pre-amplifier equalizer
35	EQ11	1.0	/// M/N Vcc /// GND	Tre ampliner equalizer
28	NF2	1.0	\$ 51k \$ 55	Pre-amplifier NF
34	NF1	1.0	GND ⁷⁷⁷ ▼ Vref	The diffipulation
29	R1	1.0	- Vcc Ζιν=100kΩ	Pre-amplifier reverse-1 channel input
30	R2	1.0	100 100 100 VCC T 33 T 100 100 100 100 100 100 100 100 100 1	Pre-amplifier reverse-2 channel input
32	F2	1.0	(3) 100k 100k Vref 0 F/R	Pre-amplifier forward-2 channel input
33	F1	1.0	S F/H	Pre-amplifier forward-1 channel input
31	Vref	1.0	RF Vcc 31 gnd mgnd	Vref amplifier output Zo≑10 Ω

*When GND is connected outside IC

Pin No.	Pin name	DC voltage	Equivalent circuit	Function
37 39	Pre OUT1	1.0	30p FRF 37 37 39 GND GND GND GND	Pre-amplifier output Zo≒ 130 Ω (for TC) Zo=100kΩ (for TU)
40	PWR IN2	1.0	40	Power amplifier input Zin=30kΩ
43	B.B AGC	-	The second secon	Controls AGC level during bass boost
44	В.В т	0	+B + Vcc 510 10k 10k 10k 10k 10k 10k 10k 10k 10k 1	AGC phase detection output smoothing pin during bass boost

Pin No.	Pin name	DC voltage	Equivalent circuit	Function
45	AVLS τ	0	#B Vcc Vcc PRF 100k 100k 100k 100k 100k 100k 100k 100	Detector output smoothing pin during AVLS
47	AVLS IN	1.0	10p 8 PF Vcc 8 198k 198k 125k \$300 \$100k Vref	AVLS input AVLS ON / OFF switching

Electrical characteristics

(unless otherwise noted, +B = 1.3V, Vcc = 2.3V, f = 1kHz, $PreOutR_L = 5k\Omega$, $PWROutR_L = 16\Omega$ (OCL), $Ta = 25^{\circ}C$, and measurement condition pertaining to ripple: Vcc and +B are common-mode input)

Parame	eter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
⟨Total⟩							
		lcc1B	_	3.0	4.5	mA	Power On, PWR-Mute OFF, TC
		lcc1V	_	4.9	6.0	I IIIA	B.B-OFF, AVLS-OFF
		lcc2B	_	0.3	8.0	mA	Power On, PWR-Mute ON, TC
Quiescent curre	ent	lcc2V	_	4.1	5.5	IIIA	B.B-OFF, AVLS-OFF
Quiosconi curre	,,,,	lcc3B	_	3.0	4.5	mA	Power On, PWR-Mute OFF, Tuner
		lcc3V	_	4.2	5.5	111/4	B.B-OFF, AVLS-OFF
		lcc4B	_	0	5.0	μΑ	Power OFF, PWR-Mute OFF, TC
		lcc4V	_	0	5.0	μΑ.	B.B-OFF, AVLS-OFF
Current consum	nption at	lcc5B	_	14.0	15.5	mA	PWR input=-45.8dBV
0.5mW		lcc5V	_	4.9	6.0	IIIA	OCL, TC, B.B-OFF, AVLS-OFF
⟨Pre block⟩							
Closed-loop vol	tage gain	Gvc1	34.6	35.6	36.6	dB	Vo=-20.0dBv
Max. output vol	tage	Vom1	185	250	_	mV	+B=0.9V, Vcc=1.7V, THD=1%
Total harmonic	distortion	THD1	_	0.12	0.5	%	+B=0.9V, Vcc=1.7V, Vo=-20.0dBv
Input reduced n	oise voltage	Vnin	_	1.25	2.0	μ Vrms	Rg=1.0kΩ, DIN-AUDIO Converted using NAB 1kHz gain
Crosstalk between	en channels	CTc1	65	_	_	dB	Do= -20.0 dBv, Rg= 1 k Ω
Crosstalk between	en F/R	CTfr	68	_	_	dB	1kHz BPF+DIN-AUDIO
AMS threshold	Mute - OFF	amsP	- 69.5	— 67.0	- 64.5	dBv	Cams=2.2 μ F, Rams=0 Ω , TU-ON
ANO theshold	Mute - ON	amsF	−62.5	-60.0	-57.5	ubv	PRE OUT input value, Vansout > 0.3V
Ripple leak (Pre	e+R.F.)	RL1	_	_	—76	dBv	+B=1.0V+(-26dBv), f=130Hz Vcc=2.0V+(-20dBv), f=130Hz Irf=-1.5mA 130Hz BPF+DIN-AUDIO
Pre-muting attenuation		Mute1	75	_	_	dB	Vcc=1.7V, Rg=1kΩ, Vo=-20dBv 1kHz BPF+DIN-AUDIO
Metal-f characte	eristic	ΔGvM	-5.44	-4.54	-3.64	dB	Deviation at 10kHz, Vo=-20dBv

ONot designed for radiation resistance.

(unless otherwise noted, +B = 1.3V, Vcc = 2.3V, f = 1kHz, $PreOutR_L = 5k\Omega$, $PWROutR_L = 16\Omega$ (OCL), $Ta = 25^{\circ}C$, and measurement condition pertaining to ripple: Vcc and +B are common-mode input)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
⟨Power block⟩						
Closed-loop voltage gain	Gvc2	22.5	24.0	25.5	dB	.,
Interchannel balance	СВ	-1.5	0.0	1.5	ub	Vo=-20.0dBv
Output power	Po	6.5	10.0	_	mW	+B=1.5V, THD=10%, R∟=16Ω
Total harmonic distortion 1	THDp1	_	0.3	0.9	%	Po=1mW, 400~30kHz BPF
Total harmonic distortion 2	THDp2	_	0.4	1.0	%	Po=1mW, f=10kHz, 30kHz LPF
Output noise voltage	V _{NO}	_	19.0	32.0	μ Vrms	Rg=600Ω, DIN-AUDIO
Crosstalk	CTc2	28.0	_	_	dB	Rg=3.3Ω, Vo=-40dBv 1kHz BPF+DIN-AUDIO
Ripple leak	RL2	_	-92.5	-87.0	dBv	+B=1.0V+(-26dBv) , f=130Hz Vcc=2.0V+(-20dBv) , f=130Hz Rg=600Ω, 130HzBPF, Irf=-1.5mA
Muting attenuation	Mute2	80	_	_	dB	f=1kHz, Vo=-20dBv B.B-MAX, 1kHz BPF+DIN-AUDIO
Input resistance	ZIN	25	30	35	kΩ	_
DC offset voltage	ΔVo	-25	0.0	15	mV	A/B-Amp in relation to C-Amp
⟨Ripple filter⟩						
Ripple rejection	RR	26.0	_	_	dB	Vcc=2.0V+(-20dBv) , f=130Hz 130Hz BPF+DIN-AUDIO, Irf=-1.5mA
DC output voltage	Vıf	1.42	1.50	_	V	Vcc=1.7V, Irf=0mA
⟨Boost⟩						
Boost ON / OFF voltage gain deviation	ΔΒ.Β	-2.0	0.0	1.0	dB	f=1kHz, V _{IN} =-60dBv
Boost amount 1*	BG1	17.5	20.0	_	dB	f=50Hz, V _{IN} =-60dBv, B.B-MAX
Boost amount 2**	BG2	3.7	5.2	6.7	dB	f=10kHz, V _{IN} =-60dBv, B.B-MAX
Boost amount 3*	BG3	5.0	6.5	8.0	dB	f=50Hz, V _{IN} =-60dBv, B.B-MID
Total harmonic distortion	THDB	_	0.3	1.0	%	f=1kHz, V _{IN} =-40dBv, 30kHz LPF
Ripple leak	RLB	_	-82.5	- 75.0	dBv	$^{+}$ B=1.0V+(-26dBv) , f=130Hz Vcc=2.0V+(-20dBv) , f=130Hz Rg=600 Ω , 130Hz BPF+DIN-AUDIO

^{*} This is the amount of boost in relation to a gain of 1kHz, when the secondary LPF (low-pass filter) is attached as specified by the measurement circuit example.

** This is the amount of boost in relation to a gain of 1kHz, when the HPF (high-pass filter) is attached as specified by the measurement circuit example.

(unless otherwise noted, +B=1.3V, Vcc=2.3V, f=1kHz, $PreOutR_L=5k\Omega(OCL)$, $PWROutR_L=16\Omega$ (OCL), $Ta=25^{\circ}C$)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions		
⟨AVLS⟩								
AVLS suppression level	AVo	-44.0	-41.0	-40.0	dBv	$V_{IN}=-30dBv$ Rav=6.8k Ω , RL=16 Ω		
AVLS start input level	AVın	-67.8	-64.8	-61.8	dBv	V_{IN} =-64.8dBv Rav=6.8k Ω , RL=16 Ω		
AVLS distortion	AVTHD	_	0.4	1.5	%	V_{IN} =-20dBv, B.B-OFF Rav=6.8k Ω , RL=16 Ω		
BEEP output level	VBeep	—61	-58	-55	dBv	R _L =16Ω, IBeep=5 μ A _{O-P} f=1kHz		

Conditions applied to control pins

(Unless otherwise noted, +B = 0.9V, Vcc = 1.7V, f = 1kHz, $PreOutR_L = 5k\Omega$, $PWROutR_L = 16\Omega$ (OCL), $Ta = 25^{\circ}C$)

Param	neter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
⟨Pre block⟩							
	Tuner		0.77	_	7.0	V	HIGH
Tuner / TC	TC	SW1	-0.2	_	0.4	V	LOW / OPEN
	Iswin		4	9	15	μΑ	V11pin=0.77V
	FWD		0.65	_	7.0	V	HIGH / OPEN
FWD / REV	REV	SW2	-0.2	_	0.2	٧	LOW
	Iswout		0.5	2.3	3.5	μΑ	V13pin=0.2V
	MTL		0.7	_	7.0	V	HIGH / OPEN
MTL / NOR	NOR	SW3	-0.2	_	0.2	V	LOW
	Iswout		0.5	2.3	3.5	μΑ	V42pin=0.2V
⟨Power block⟩							•
	ON		0.77	_	7.0	V	HIGH
PWR ON / OFF	OFF	SW4	-0.2	_	0.4	V	LOW / OPEN
0117 011	Iswin		5	11	17	μΑ	V12pin=0.77V
	OFF	SW5	0.65	_	7.0	V	HIGH
MUTE ON / OFF	ON		-0.2	_	0.2	V	LOW
0117 011	Iswin		_	0.25	1.0	μΑ	V10pin=0.65V
	ON		0.75	_	7.0	V	HIGH
B.B.	OFF		-0.2	_	0.3	٧	LOW
B.B ON / OFF	Iswout	SW6	_	0.0	1.0	μΑ	V9pin=0.3V
0,,,,	Iswin1		_	0.0	1.0	μΑ	V9pin=1.5V, V10pin=0.6V
	Iswin2		3	7	11	μΑ	V10pin=0V
	ON		_	_	_	V	PWR1 and PWR2 signals input
AVLS ON / OFF	OFF	SW7	-0.2	_	0.2	V	LOW
	Iswout		5	25	30	μA	V47pin=0.2V
-	MAX		0.65	_	7.0	V	HIGH / OPEN
B.B MAX / MID	MID	SW8	-0.2	_	0.2	V	LOW
	Іswouт		0.5	2.3	3.5	μΑ	V8pin=0.2V

Iswan: Indicates current flowing to the interior of the IC. Iswour: Indicates current flowing to the exterior of the IC.

Measurement circuit

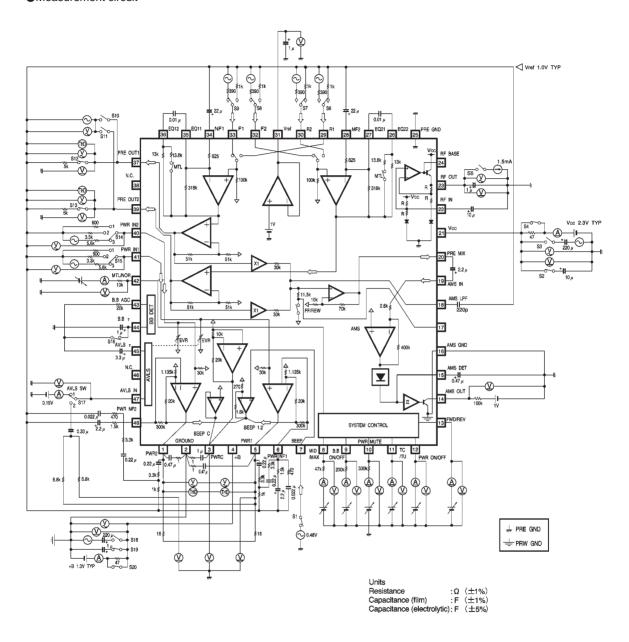
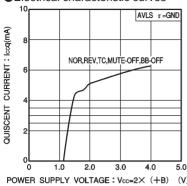


Fig.1

Electrical characteristic curves

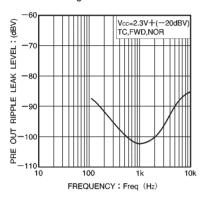


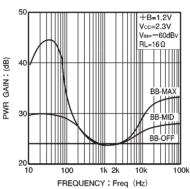
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Fig.2 Quiescent current vs. power supply voltage

Fig.3 PRE gain vs. frequency

Fig.4 Total harmonic distortion





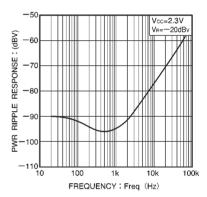


Fig.5 PRE ripple leak characteristics

Fig.6 PWR gain vs. frequency

Fig.7 PWR ripple leak characteristics

External dimensions (Units: mm)

